

## MOTOROLA

## **Crystal Oscillator**

The MC12061 is for use with an external crystal to form a crystal controlled oscillator. In addition to the fundamental series mode crystal, two bypass capacitors are required (plus usual power supply pin bypass capacitors). Translators are provided internally for MECL and TTL outputs.

- Frequency Range = 2.0 to 20 MHz
- Temperature Range = 0 to + 70°C
- Single Supply Operation: +5.0 Vdc or -5.2 Vdc
- Three Outputs Available:
  - 1. Complementary Sine Wave (600 mVpp typ)
  - 2. Complementary MECL
  - 3. Single Ended TTL

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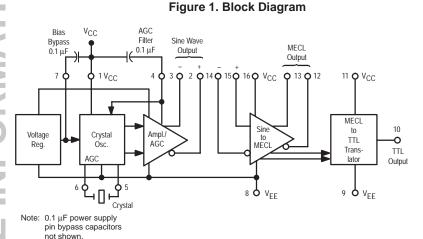
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## MC12061

### **CRYSTAL OSCILLATOR**

SEMICONDUCTOR **TECHNICAL DATA** 



**P SUFFIX** PLASTIC PACKAGE CASE 648

### **ORDERING INFORMATION**

Device	Operating Temperature Range	Package
MC12061P	$T_A = 0^\circ$ to +70°C	Plastic

### **TYPICAL CIRCUIT CONFIGURATIONS**

Note: 0.1 µF power supply pin bypass capacitors not shown.

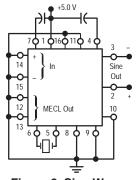


Figure 2. Sine Wave Output

### 5.0 V 2 Out -C 3 Ó TTI ŀС Out 14

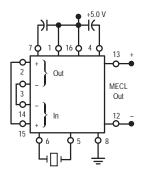
Figure 3. MTTL Output

Characteristic

Mode of Operation

Frequency Range

Series Resistance, R1



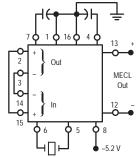


Figure 4. MECL Output (+5.0 V Supply)

Figure 5. MECL Output (-5.2 V Supply)

MC12061

**Fundamental Series Resonance** 

### CRYSTAL REQUIREMENTS

Note: Start-up stabilization time is a function of crystal series resistance. The lower the resistance, the faster the circuit stabilizes.

2.0 MHz - 20 MHz Minimum at Fundamental Maximum Effective Resistance RE(max) 155 ohms

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### **ELECTRICAL CHARACTERISTICS**

Characteristic	Test Limits									
Characteristic		Pin Under	0	°C		+25°C		+7	5°C	Unit
Characteristic	Symbol	Test	Min	Max	Min	Тур	Max	Min	Max	
Power Supply Drain Current	ICC	1	-	-	13	16	19	-	-	mAdc
		1	-	-	18	23	28	-	-	
		11 16		-	- 13	3.0 16	4.0 19		-	
Input Current	linH	14 15				-	250 250			μAdc
	linL	14 15				-	1.0 1.0	-		μAdc
Differential Offset Voltage	ΔV	4 to 7 2 to 3	-	-	40 200	_ 0	325 +200	-		mAdc
Output Voltage Level	Vout	2 3				3.5 3.5				Vdc
Logic '1' Output Voltage	VOH1 (Note 1)	12 13	4.0 4.0	4.16 4.16	4.04 4.04		4.19 4.19	4.1 4.1	4.28 4.28	Vdc
	V <sub>OH2</sub>	10	2.4	-	2.4	-	-	2.4	-	
Logic '0' Output Voltage	V <sub>OL1</sub> (Note 1)	12 13	2.98 2.98	3.43 3.43	3.0 3.0		3.44 3.44	3.02 3.02	3.47 3.47	Vdc
	V <sub>OL2</sub>	10 10		0.5 0.5			0.5 0.5		0.5 0.5	
Logic '1' Threshold Voltage	VOHA	12 13	3.98 3.98	-	4.02 4.02	-		4.08 4.08		Vdc
Logic '0' Threshold Voltage	VOLA	12 13	-	3.45 3.45	-	-	3.46 3.46	-	3.49 3.49	Vdc
Output Short Circuit Current	los	10	20	60	20	_	60	20	60	mAdc



### ELECTRICAL CHARACTERISTICS (continued)

			TEST VOLTAGE/CURRENT VALUES								
	Volts										
(	Test Temp	perature	VIHmax	VILmin	VIHAmin	VILAmax	VIHT	VCCL	]		
		0°C	4.16	3.19	3.86	3.51	4.0	4.75			
		+25°C	4.19	3.21	3.90	3.52	4.0	4.75			
		+75°C	4.28	3.23	3.96	3.55	4.0	4.75			
		Pin	TE	ST VOLTAGE	APPLIED	TO PINS LIS	TED BELC	w			
Characteristic	Symbol	Under Test	V <sub>IHmax</sub>	V <sub>ILmin</sub>	V <sub>IHAmin</sub>	V <sub>ILAmax</sub>	VIHT	V <sub>CCL</sub>	Gnd		
Power Supply Drain Current	ICC	1	_	_	-	-	_	_	8		
		1 11 16	- 14 -	- 15 -	- - -	- - -	- - -	- - -	8 8,9 8		
Input Current	linH	14 15	14 15	15 14					8 8		
	linL	14 15	15 14			-			8,14 8,15		
Differential Offset Voltage	ΔV	4 to 7 2 to 3	-			-	5,6 4	-	8 -		
Output Voltage Level	Vout	2 3	-	-	-	-	4 4	-	8 8		
Logic '1' Output Voltage	VOH1 (Note 1)	12 13	14 15	15 14					8 8		
	VOH2	10	15	14	-	-	-	11,16	8,9		
Logic '0' Output Voltage	VOL1 (Note 1)	12 13	15 14	14 15		-			8 8		
	V <sub>OL2</sub>	10 10	14 14	15 15		-	-	11,16 —	8,9 8,9		
Logic '1' Threshold Voltage	Vона	12 13			14 15	15 14	-	-	8 8		
Logic '0' Threshold Voltage	VOLA	12 13			15 14	14 15	-		8 8		
Output Short Circuit Current	los	10	15	14	-	-	_	11,16	8,9,10		

**NOTE:** 1. Devices will meet standard MECL logic levels using  $V_{EE} = -5.2Vdc$  and  $V_{CC} = 0$ .



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### ELECTRICAL CHARACTERISTICS (continued)

	TEST VOLTAGE/CURRENT VALUES							
			V	/olts		mA		
	@ Test Tem	perature	V <sub>CC</sub>	VCCH	IOL	ЮН	ΙL	
		0°C	5.0	5.25	16	-0.4	-2.5	
		+25°C	5.0	5.25	16	-0.4	-2.5	
		+75°C	5.0	5.25	16	-0.4	-2.5	
		Pin	TEST	VOLTAGE AP	PLIED TO PIN	IS LISTED BE	LOW	
Characteristic	Symbol	Under Test	vcc	VCCH	I <sub>OL</sub>	Іон	۱ <sub>IL</sub>	Gnd
Power Supply Drain Current	ICC	1	1	-	-	-	-	8
		1 11 16	1 11,16 16			_ _ _	- - -	8 8,9 8
Input Current	linH	14 15	16 16					8 8
	linL	14 15	16 16					8,14 8,15
Differential Offset Voltage	ΔV	4 to 7 2 to 3	1 _				-	8 –
Output Voltage Level	Vout	2 3	1 1					8 8
Logic '1' Output Voltage	VOH1 (Note 1)	12 13	16 16				12 13	8 8
	V <sub>OH2</sub>	10	-	-	-	10	-	8,9
Logic '0' Output Voltage	VOL1 (Note 1)	12 13	16 16				12 13	8 8
	V <sub>OL2</sub>	10 10	-	_ 11,16	10 10			8,9 8,9
Logic '1' Threshold Voltage	Voha	12 13	16 16				12 13	8 8
Logic '0' Threshold Voltage	VOLA	12 13	16 16				12 13	8 8
Output Short Circuit Current	IOS	10	_	_	_	_	_	8,9,10

**NOTE:** 1. Devices will meet standard MECL logic levels using  $V_{EE} = -5.2$ Vdc and  $V_{CC} = 0$ .



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Figure 6. AC Characteristics – MECL and TTL Outputs

### +200 mV $V_{CC} = +2.0 \, Vdc$ 80% 0.1 µF 50% Input (Pin 15) 20% -200 mV t + + t -11 16 450 15 0 50% TTL Output Pulse Generator (EH 137 or Equiv) PRF = 2.0 MHz (Pin 10) 450 12 t++ t. ~~~ 80% $t + = t - = 2.0 \pm 0.2$ ns 50% MECL Output 20% 10 1.2 k (Pin 13) ᠕᠕ С t+ Ţ t - -400 MECL Output • + 2.0 Vdc 80% 9 **¢** 8 w (Pin 12) 50% MMD6150 20% C<sub>T</sub>; or Equiv 0.1μF **木** All input and output cables to the scope $C_T = 15 \, pF$ = total parasitic capacitance which MMD7000 are equal lengths of 50 $\Omega$ coaxial cable. includes probe, wiring, and load capacior Equiv tance. Unused outputs are connected to a 50 $\Omega$ $V_{EE} = -3.0 \text{ Vdc}$ ±1% resistor to ground. – 3.0 Vdc

			Test Limits							TEST VOLTAGES/WAVEFORMS APPLIED TO PINS LISTED BELOW:					
		Pin Under	0°	°C		+25°C	;	+7	5°C						
Characteristic	Symbol	Test	Min	Max	Min	Тур	Мах	Min	Max	Unit	Pulse In	Pulse Out	+2.0 Vdc	-3.0 Vdc	Gnd
Propagation Delay	$t_{15+10+} \\ t_{15-10-} \\ t_{15+12-} \\ t_{15-12+} \\ t_{15+13+} \\ t_{15-13-} \\ t_{15-13-1} \\ t_{15-$	10 10 12 12 13 13		22 19 5.2 5.0 4.8 5.0		17 12 4.3 3.7 4.0 4.0	25 18 5.5 5.2 5.0 5.0		27 18 5.8 5.2 5.2 5.2 5.1	ns	15	10 10 12 12 13 13	11,16	8,9	14
Rise Time	<sup>t</sup> 12+ <sup>t</sup> 13+	12 13	—	4.0 4.0	—	3.0 3.0	4.0 4.0	—	4.4 4.4	ns ns	15 15	12 13	11,16 11,16	8,9 8,9	14 14
Fall Time	t <sub>12</sub> - t <sub>13</sub> -	12 13		4.0 4.0	_	3.0 3.0	4.0 4.0	_	4.0 4.0	ns ns	15 15	12 13	11,16 11,16	8,9 8,9	14 14

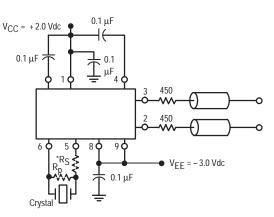
	Pin Under	+25°C			TEST VOLTA TO PINS LIS	GE APPLIED TED BELOW
Characteristic	Test	Min	Тур	Unit	+2.0 Vdc	-3.0 Vdc
Sine Wave Amplitude						
	2	650	750	mVp-p	1	8,9
	3	650	750			

### Figure 7. AC Test Circuit – Sine Wave Output

All output cables to the scope are equal lengths of 50  $\Omega$  coaxial cable. All unused cables must be terminated with a 50  $\Omega$   $\pm$  1% resistor to ground.

 $450\,\Omega$  resistor and the scope termination impedance constitute a 10:1 attenuator probe.

- Crystal Reeves Hoffman Series Mode,
  - Series Resistance Minimum at Fundamental f = 10 MHz
    - $R_E = 5 \Omega$
- ${}^{*}R_{S} = 15 \ k\Omega$  is inserted only for test purposes. When used with the above specified crystal, it guarantees oscillation with any crystal which has an equivalent series resistance  $\leq 155 \ \Omega$



 $<sup>\</sup>textrm{R}_\textrm{p}\textrm{:}$  will improve start up problems value: 200–500  $\Omega$ 



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**OPERATING CHARACTERISTICS** 

The MC12061 consists of three basic sections: an oscillator with AGC and two translators (NO TAG). Buffered complementary sine wave outputs are available from the oscillator section. The translators convert these sine wave outputs to levels compatible with MECL and/or TTL.

Series mode crystals should be used with the oscillator. If it is necessary or desirable to adjust the crystal frequency, a reactive element can be inserted in series with the crystal an inductor to lower the frequency or a capacitor to raise it. When such an adjustment is necessary, it is recommended that the crystal be specified slightly lower in frequency and a series trimmer capacitor be added to bring the oscillator back on frequency. As the oscillator frequency is changed from the natural resonance of the crystal, more and more dependence is placed on the external reactance, and temperature drift of the trimming components then affects overall oscillator performance.

The MC12061 is designed to operate from a single supply — either +5.0 Vdc or -5.2 Vdc. Although each translator has separate V<sub>CC</sub> and V<sub>EE</sub> supply pins, the circuit is NOT designed to operate from both voltage levels at the same time. The separate V<sub>EE</sub> pin from the TTL translator helps minimize transient disturbance. If neither translator is being used, all unused pins (9 thru 16) should be connected to V<sub>EE</sub> (pin 8). With the translators not powered, supply current drain is typically reduced from 42 mA to 23 mA for the MC12061.

### **Frequency Stability**

Output frequency of different oscillator circuits (of a given device type number) will vary somewhat when used with a given test setup. However, the variation should be within approximately  $\pm 0.001\%$  from unit to unit.

Frequency variations with temperature (independent of the crystal, which is held at 25°C) are small — about – 0.08 ppm/°C for MC12061 operating at 8.0 MHz (see NO TAG).

### **Signal Characteristics**

The sine wave outputs at either pin 2 or pin 3 will typically range from 800 mV<sub>p-p</sub> (no load) to 500 mV<sub>p-p</sub> (120 ohm ac load). Approximately 500 mV<sub>p-p</sub> can be provided across 50 ohms by slightly increasing the dc current in the output buffer by the addition of an external resistor (680 ohms) from pin 2 or 3 to ground, as shown in Figure 9. Frequency drift is typically less than 0.0003% when going from a high-impedance load (1 megohm, 15 pF) to the 50 ohm load of Figure 9. The dc voltage level at pin 2 or 3 is nominally 3.5 Vdc with V<sub>CC</sub> = +5.0 Vdc.

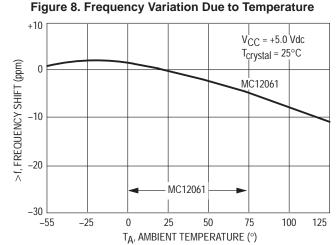
Harmonic distortion content in the sine wave outputs is crystal as well as circuit dependent. The largest harmonic (third) will usually be at least 15 dB down from the fundamental. The harmonic content is approximately load independent except that the higher harmonic levels (greater than the fifth) are increased when the MECL translator is being driven.

Typically, the MECL outputs (pins 12 and 13) will drive up to five gates, as defined in NO TAG, and the TTL output (pin 10) will drive up to ten gates, as defined in NO TAG.

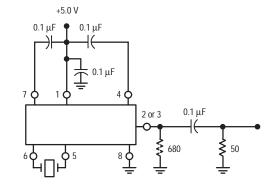
### **Noise Characteristics**

Noise level evaluation of the sine wave outputs using the circuit of NO TAG, with operation at or 9.0 MHz, indicates the following characteristics:

- Noise floor (200 kHz from oscillator center frequency) is approximately –122 dB when referenced to a 1.0 Hz bandwidth. Noise floor is not sensitive to load conditions and/or translator operation.
- Close-in noise (100 Hz from oscillator center frequency) is approximately –88 dB when referenced to a 1.0 Hz bandwidth.



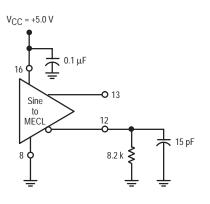
### Figure 9. Driving Low Impedance Loads

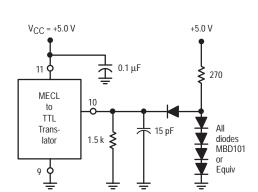


\* See text under signal characteristics.

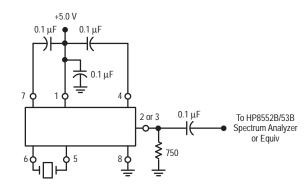


### Figure 10. MECL Translator Load Capability





### Figure 12. Noise Measurement Test Circuit



### ANALYZER SETTING

Measurement	Sweep	Bandwidth	Video Filter
Noise Floor	50 kHz/div	10 kHz	10 Hz
Close-In Noise	20 kHz/div	10 Hz	10 Hz

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Figure 11. TTL Translator Load Capability



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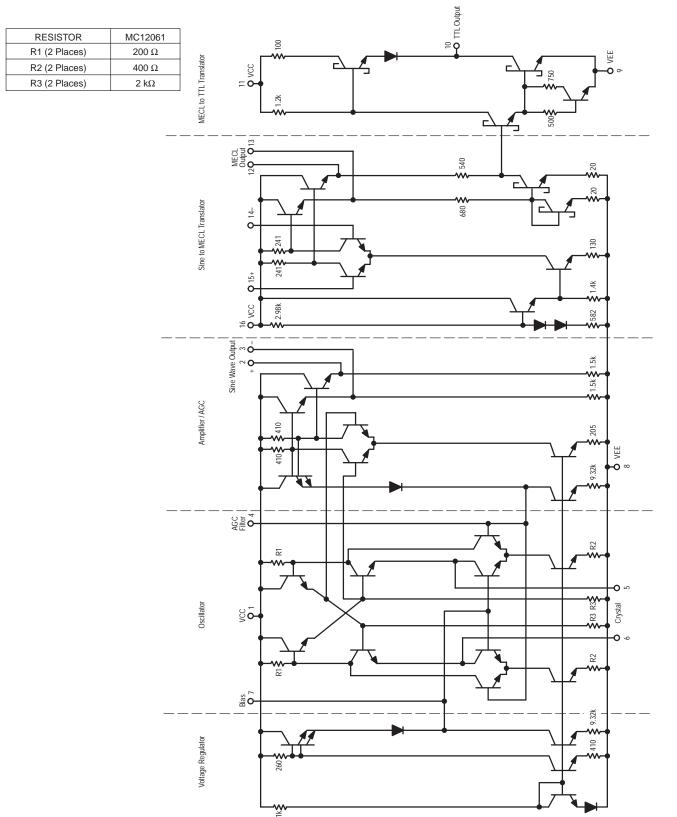
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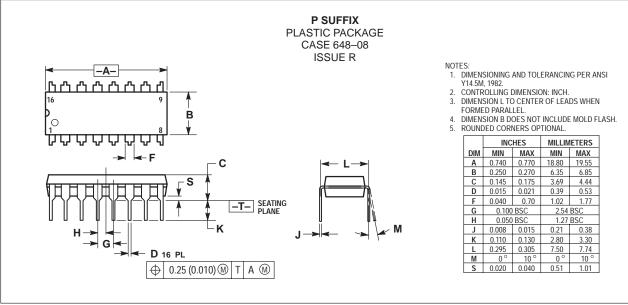
Figure 13. Circuit Schematic



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NOTES



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